

### Switch-mode Power Rectifiers

### MUR1510G, MUR1515G, MUR1520G, MUR1540G, MUR1560G, MURF1560G, SUR81520G, SUR81560G

These state-of-the-art devices are a series designed for use in switching power supplies, inverters and as free wheeling diodes.

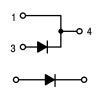
#### Features

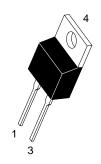
- Ultrafast 35 and 60 Nanosecond Recovery Time
- 175 °C Operating Junction Temperature
- High Voltage Capability to 600 V
- ESD Ratings:
  - ◆ Machine Model = C
  - ◆ Human Body Model = 3B
- Low Forward Drop
- Low Leakage Specified @ 150 °C Case Temperature
- Current Derating Specified @ Both Case and Ambient Temperatures
- SUR8 Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- All Packages are Pb-Free\*

#### **Mechanical Characteristics:**

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260 °C Max. for 10 Seconds

### ULTRAFAST RECTIFIERS 15 AMPERES, 100–600 VOLTS







TO-220AC CASE 221B STYLE 1

TO-220 FULLPAK CASE 221AG STYLE 1

#### **MARKING DIAGRAMS**





A = Assembly Location

Y = Year
WW = Work Week
G = Pb-Free Package
U15xx = Device Code

xx = 10, 15, 20, 40 or 60

KA = Diode Polarity

### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 7.

1

For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **MAXIMUM RATINGS**

		MUR/SUR8					
Rating	Symbol	1510	1515	1520	1540	1560	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	150	200	400	600	V
Average Rectified Forward Current (Rated V <sub>R</sub> )	I <sub>F(AV)</sub>	1:	5 @ T <sub>C</sub>	= 150 °	С	15 @ T <sub>C</sub> = 145 °C	Α
Peak Rectified Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz)	I <sub>FRM</sub>	30 @ T <sub>C</sub> = 150 °C 30 @ T <sub>C</sub> = 145 °C		Α			
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	200 150		Α			
Operating Junction Temperature and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +175		°C			

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
MUR1510 Series: Thermal Resistance Junction-to-Case Junction-to-Ambient	$R_{ hetaJC} \ R_{ hetaJA}$	1.5 73	°C/W
MURF1560: Thermal Resistance Junction-to-Case Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	4.25 75	°C/W

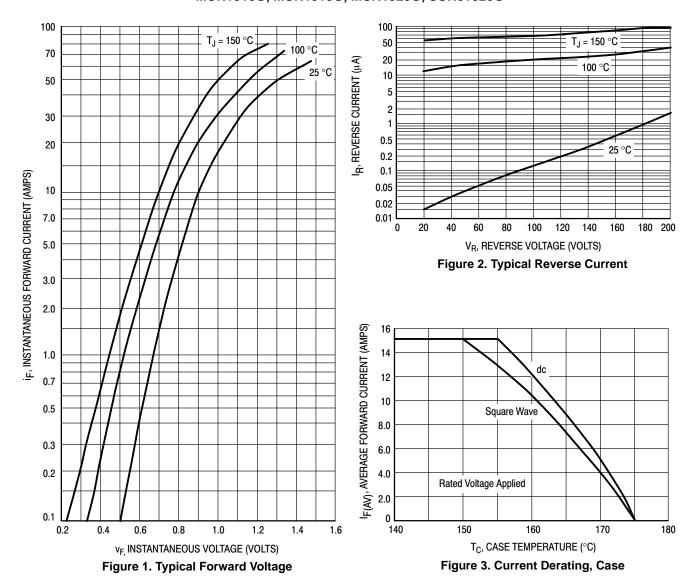
#### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	1510	1515	1520	1540	1560	Unit
Maximum Instantaneous Forward Voltage (Note 1) ( $i_F = 15$ A, $T_C = 150$ °C) ( $i_F = 15$ A, $T_C = 25$ °C)	VF		0.85 1.05		1.12 1.25	1.20 1.50	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, $T_C$ = 150 °C) (Rated DC Voltage, $T_C$ = 25 °C)	i <sub>R</sub>		500 10		500 10	1000 10	μΑ
Maximum Reverse Recovery Time (I <sub>F</sub> = 1.0 A, di/dt = 50 A/μs)	t <sub>rr</sub>		35			60	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width =  $300 \mu s$ , Duty Cycle  $\leq 2.0\%$ .

#### MUR1510G, MUR1515G, MUR1520G, SUR81520G



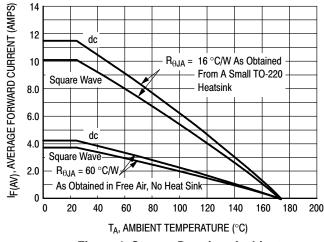


Figure 4. Current Derating, Ambient

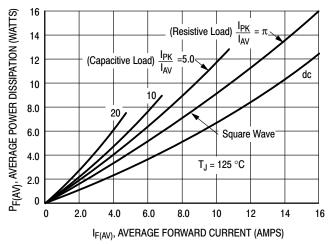


Figure 5. Power Dissipation

#### MUR1540G

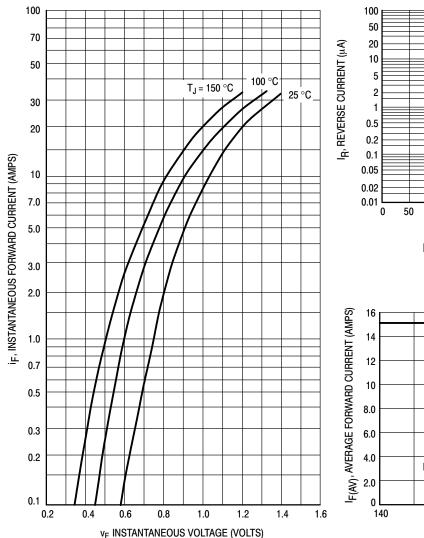
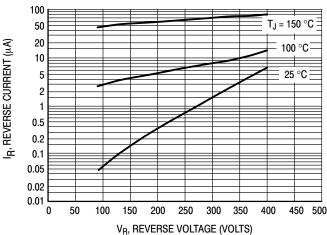


Figure 6. Typical Forward Voltage



**Figure 7. Typical Reverse Current** 

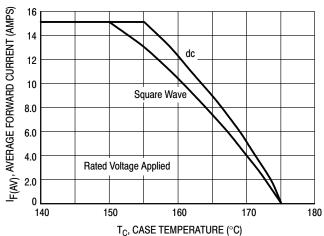


Figure 8. Current Derating, Case

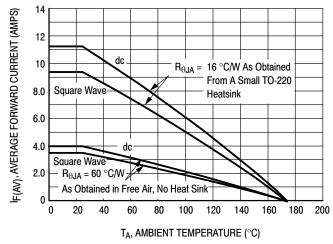


Figure 9. Current Derating, Ambient

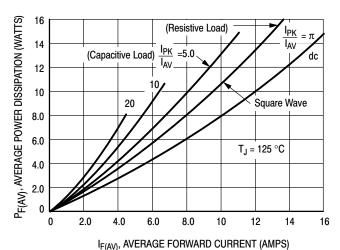


Figure 10. Power Dissipation

#### MUR1560G, MURF1560G, SUR81560G

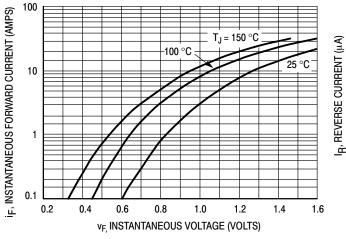
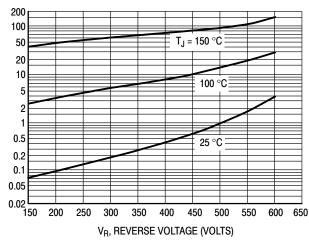


Figure 11. Typical Forward Voltage



**Figure 12. Typical Reverse Current** 

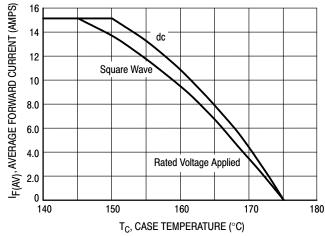


Figure 13. Current Derating, Case

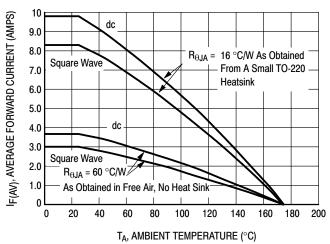


Figure 14. Current Derating, Ambient

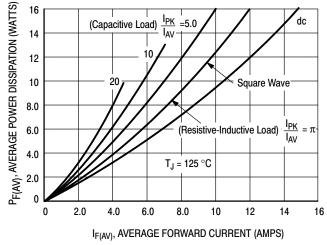
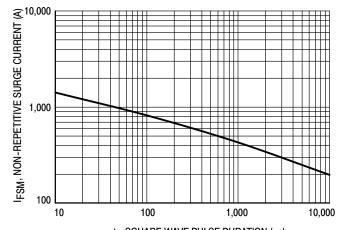


Figure 15. Power Dissipation



t<sub>p</sub>, SQUARE WAVE PULSE DURATION (μs)

Figure 16. Typical Non-Repetitive Surge Current

<sup>\*</sup> Typical performance based on a limited sample size. **onsemi** does not guarantee ratings not listed in the Maximum Ratings table.

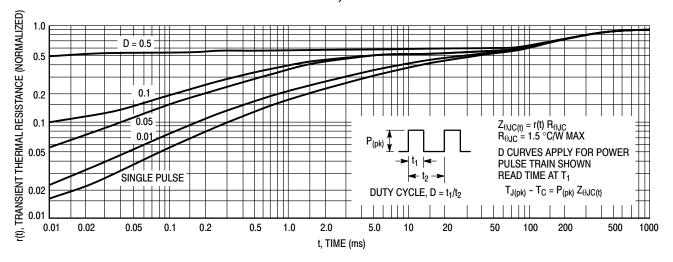


Figure 17. Thermal Response

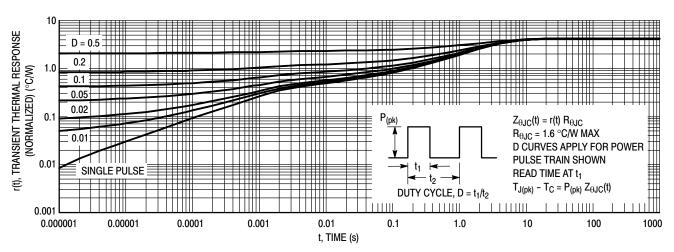


Figure 18. Thermal Response, (MURF1560G) Junction-to-Case ( $R_{\theta JC}$ )

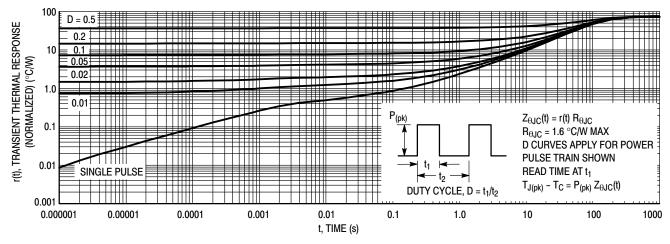


Figure 19. Thermal Response, (MURF1560G) Junction-to-Ambient (R<sub>0,JA</sub>)

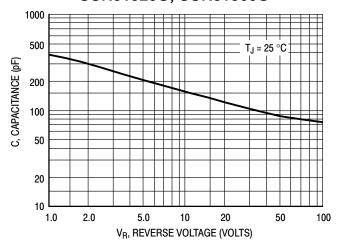


Figure 20. Typical Capacitance

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MUR1520G	TO-220AC (Pb-Free)	50 Units / Rail
MUR1540G	TO-220AC (Pb-Free)	50 Units / Rail
MUR1560G	TO-220AC (Pb-Free)	50 Units / Rail
SUR81560G	TO-220AC (Pb-Free)	50 Units / Rail
MURF1560G	TO-220FP (Pb-Free)	50 Units / Rail

#### **DISCONTINUED** (Note 2)

MUR1510G	TO-220AC (Pb-Free)	50 Units / Rail
MUR1515G	TO-220AC (Pb-Free)	50 Units / Rail
SUR81520G	TO-220AC (Pb-Free)	50 Units / Rail

<sup>†</sup> For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>2.</sup> **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on <a href="https://www.onsemi.com">www.onsemi.com</a>.

### **REVISION HISTORY**

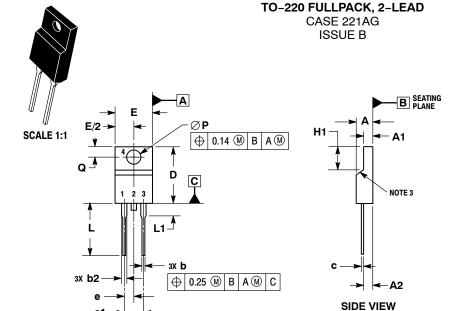
Revision	Description of Changes	Date
11	Rebranded the Data Sheet to <b>onsemi</b> format. MUR1510G, MUR1515G, SUR81520G OPNs marked as Discontinued.	10/8/2025

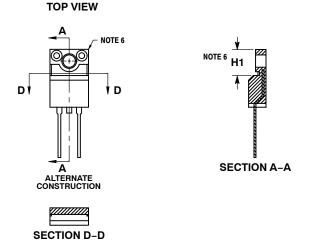
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

**DATE 27 AUG 2015** 



**e**1

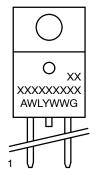




- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. CONTOUR UNCONTROLLED IN THIS AREA.
  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.
- 5. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.

SHALL NOT EXCEED 2.0					
	MILLIMETERS				
DIM	MIN	MAX			
Α	4.30	4.70			
A1	2.50	2.90			
A2	2.50	2.90			
b	0.54	0.84			
b2	1.10	1.40			
c	0.49	0.79			
D	14.22	15.88			
Е	9.65	10.67			
е	2.54	BSC			
e1	5.08	BSC			
H1	6.40	6.90			
L	12.70	14.73			
L1		2.80			
P	3.00	3.40			
Q	2.80	3.20			

#### **GENERIC MARKING DIAGRAM\***



= Assembly Location

WL = Wafer Lot

= Year

WW = Work Week

G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

DOCUMENT NUMBER:	98AON52563E	Electronic versions are uncontrolled except when accessed directly from the Document Rep Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	TO-220 FULLPACK, 2-LEA	AD	PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves brisefin and of 160 m are trademarked so defined values of services and of the confined values and of the values of the confined values and of the values of the confined values and of the values of the special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.





TO-220, 2-LEAD CASE 221B-04 ISSUE F

**DATE 12 APR 2013** 

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.620	15.11	15.75
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.82
D	0.025	0.039	0.64	1.00
F	0.142	0.161	3.61	4.09
G	0.190	0.210	4.83	5.33
Н	0.110	0.130	2.79	3.30
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
T	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

Q

STYLE 1: PIN 1. CATHODE 2. N/A 3. ANODE

STYLE 2: PIN 1. ANODE 2. N/A 3. CATHODE 4. ANODE

DOCUMENT NUMBER:	98ASB42149B	Electronic versions are uncontrolled except when accessed directly from the Document Report Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	TO-220, 2-LEAD		PAGE 1 OF 1		

onsemi and ONSEMi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales